#### TOSHIBA PHOTOCOUPLER GaAlAs IRED & PHOTO IC

# **TLP558**

ISOLATED BUS DRIVER

HIGH SPEED LINE RECEIVER

**MICROPROCESSOR SYSTEM INTERFACES** 

MOS FET GATE DRIVER

TRANSISTOR INVERTER

The TOSHIBA TLP558 consists of a GaAlAs light emitting diode and integrated high gain, high speed photodetector.

This unit is 8-lead DIP package.

The detector has a three state output stage that provides source drive and sink drive, and built-in Schmitt trigger. The detector IC has an internal shield that provides a guaranteed common mode transient immunity of  $1000\mathrm{V}/\mu\mathrm{s}$ . TLP558 is inverter logic type. For buffer logic type, TLP555 is in line-up.

• Input Current : IF=1.6mA (MAX.)

• Power Supply Voltage: VCC=4.5~20V

• Switching Speed :  $t_{pHL}$ ,  $t_{pLH} = 400$ ns (MAX.)

• Common Mode Transient Immunity

:  $\pm 1000 \text{V} / \mu \text{s} (\text{MIN.})$ 

• Guaranteed Performance Over Temperature

: −25~85°C

• Isolation Voltage : 2500V<sub>rms</sub> (MIN.)

• UL Recognized : UL1577, File No. E67349

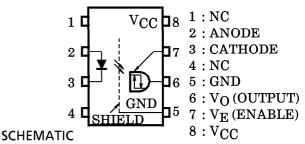
Unit in mm

8 7 6 5
1 2 3 4
9.66 ± 0.25
1.2 ± 0.15
0.5 ± 0.1
2.54 ± 0.25

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Weight: 0.54g

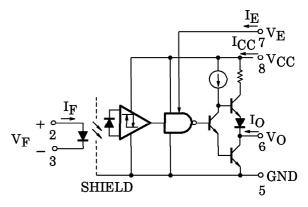
#### PIN CONFIGURATION (TOP VIEW)



TRUTH TABLE (Positive Logic)

INPUT	ENABLE	OUTPUT
Н	н	L
L	н	н
Н	L	${f z}$
L	L	Z

A  $0.1\mu F$  bypass capacitor must be connected between pins 8 and 5 (See note 9).



MAXIMUM RATINGS (No Derating Required up to 85°C unless otherwise noted)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
	Foward Current	$I_{\mathbf{F}}$	10	mA
LED	Peak Transient Forward Current (Note 1)	$I_{\mathrm{FPT}}$	1	A
	Reverse Voltage	$v_{R}$	5	V
	Output Current	IO	40/-25	mA
ا ي	Peak Output Current (Note 2)	$I_{OP}$	80/-50	mA
T0	Output Voltage	$v_{\mathbf{O}}$	-0.5~20	V
DETECTOR	Supply Voltage	$v_{CC}$	-0.5~20	V
ET	Three State Enable Voltage	$V_{\mathbf{E}}$	-0.5~20	V
	Output Power Dissipation (Note 3)	PO	100	mW
	Total Package Power Dissipation (Note 4)	${ m PT}$	200	mW
0	perating Temperature Range	$T_{ m opr}$	-40~85	°C
St	orage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C
Le	ead Solder Temperature (10s)**	T <sub>sol</sub>	260	°C
Is	olation Voltage (AC, 1min., R.H.≤60%, Ta=25°C) (Note 5)	$\mathrm{BV}_{\mathbf{S}}$	2500	Vrms

- (Note 1) Pulse Width  $\leq 1 \mu s$ , 300pps.
- (Note 2) Pulse Width  $\leq 5\mu$ s, Duty Ratio  $\leq 0.025$ .
- (Note 3) Derate 1.8mW/°C above 70°C ambient temperature.
- (Note 4) Derate 3.6mW/°C above 70°C ambient temperature.
- (Note 5) Device considered a two terminal device: pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

#### RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Input Current, ON	I <sub>F (ON)</sub>	2*	_	5	mA
Input Voltage, OFF	V <sub>F (OFF)</sub>	0		0.8	V
Supply Voltage	$v_{CC}$	4.5		20	V
Enable Voltage High	$ m v_{EH}$	2.0		20	V
Enable Voltage Low	$ m V_{EL}$	0		0.8	V
Fan Out (TTL Load)	N	_	_	4	_
Operating Temperature	${ m T_{opr}}$	-25	_	85	°C

<sup>\* 2</sup>mA condition permits at least 20% CTR degradation guardband. Initial switching threshold is 1.6mA or less.

<sup>\*\* 1.6</sup>mm below seating plane.

ELECTRICAL CHARACTERISTICS (Unless otherwise specified, Ta =  $-25 \sim 85$ °C, V<sub>CC</sub> =  $4.5 \sim 20$ V)

CHARACTERISTIC	SYMBOL	TEST C	MIN.	TYP.*	MAX.	UNIT		
Input Forward Voltage	$V_{\mathbf{F}}$	$I_{ m F}\!=\!5{ m mA},~{ m Ta}\!=\!25^{\circ}{ m C}$			_	1.55	1.7	V
Temperature Coefficient of Forward Voltage	ΔV <sub>F</sub> /ΔTa				ı	-2.0	l	mV/°C
Input Reverse Current	${ m I}_{ m R}$	$V_R = 5V$ , $T_a = 2$	25°C		ı	_	10	$\mu$ <b>A</b>
Input Capacitance	$\mathrm{c_{T}}$	$V_{\mathbf{F}} = 0$ , $\mathbf{f} = 1\mathbf{M}\mathbf{H}$	Hz, Ta	=25°C	-	45		рF
Output Leakage Current	т	$V_{\mathbf{F}}=0$ ,	V <sub>O</sub> =	$V_{\rm E} = 5.5 \rm V$	-	_	100	_
$(V_O > V_{CC})$	ІОНН	$V_{\rm CC} = 4.5 V$	$V_{O} =$	$V_{\rm E} = 20 \rm V$	ı	0.01	500	$\mu$ A
Logic Low Output Voltage	$v_{OL}$	$I_{ m OL}$ =6.4mA, I $V_{ m E}$ =2V			l	0.4	0.5	V
Logic High Output Voltage	V <sub>OH</sub>	$I_{OH} = -2.6$ mA $V_{E} = 2$ V	, V <sub>F</sub> =	=0.8V	2.4	3.3	ı	V
Logic Low Enable Current	${ m I_{EL}}$	$V_{ m E}\!=\!0.4{ m V}$				-0.13	-0.32	mA
		$V_{ m E}\!=\!2.7{ m V}$			-	_	20	
Logic High Enable Current	${ m I_{EH}}$	$V_{ m E}\!=\!5.5{ m V}$	ı	-	100	$\mu$ A		
		$V_{ m E}\!=\!20{ m V}$	1	0.01	250			
Logic Low Enable Voltage	$ m v_{EL}$		_		ı	-	0.8	V
Logic High Enable Voltage	$ m v_{EH}$	_			2.0	_		V
Logic Low Supply Current	$I_{CCL}$	$I_{\mathbf{F}} = 5 \text{mA} \qquad \frac{V_{\mathbf{CC}} = V_{\mathbf{E}} = 5.5 \text{V}}{V_{\mathbf{CC}} = V_{\mathbf{F}} = 20 \text{V}}$			_	4.0	6.0 7.5	mA
				$=V_{E}=20V$	_	4.6	6.0	
Logic High Supply Current	$I_{CCH}$	$V_{\mathbf{F}} = 0V$		$=V_{E}=5.5V$ $=V_{E}=20V$	_	4.2 4.7	7.5	mA
	I <sub>OZL</sub>	$V_{\mathbf{F}} = 0V$ $V_{\mathbf{E}} = 0.8V$		$V_{O} = 0.4V$		_	-20	
High Impedance State	I <sub>OZH</sub>	T		$V_O = 2.4V$	-	_	20	$\mu$ <b>A</b>
Output Current		$I_{\mathbf{F}} = 5 \text{mA}$ $V_{\mathbf{E}} = 0.8 \text{V}$		$V_O = 5.5V$	ı	_	100	
		VE-0.6V		$V_O = 20V$	_	1	500	
Logic Low Short Circuit	_	$I_F = 5 \text{mA}$	V <sub>O</sub> =	$V_{\rm CC} = 5.5 \rm V$	25	55	_	
Output Current (Note 6)	$I_{OSL}$	$\overline{\mathrm{V_E}} = 2\mathrm{V}$	$V_{O} = V_{CC} = 20V$		40	80	_	mA
Logic High Short Circuit	-	$V_{\mathbf{F}} = 0V, V_{\mathbf{O}} = GND$		T T	-10	-25	_	^
Output Current (Note 6) IOSH		$V_{\rm E}$ =2V $V_{\rm CC}$ =20V		-25	-60	ı	mA	
Input Current Logic Low Output	${ m I_{FL}}$	$V_E = 2V, I_O = 6.4 \text{mA}$ $V_O < 0.4 V$			_	0.4	1.6	mA
Input Voltage Logic High Output	$v_{ m FH}$	$V_{E} = 2V, I_{O} = -2.6 \text{mA}$ $V_{O} > 2.4 \text{V}$			0.8	_	_	V

## ELECTRICAL CHARACTERISTICS (Unless otherwise specified, Ta = $-25 \sim 85^{\circ}$ C, V<sub>CC</sub> = $4.5 \sim 20$ V)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.*	MAX.	UNIT
Input Current Hysteresis	$I_{ m HYS}$	$V_{CC} = V_E = 5V$	_	0.05	1	mA
Resistance (Input-Output)	R.Q	$V_S = 500V, R.H. \le 60\%$ $T_a = 25^{\circ}C$ (Note 5)	$5 \times 10^{10}$	$10^{14}$	l	Ω
Capacitance (Input-Output)	$c_8$	V <sub>S</sub> =0, f=1MHz, Ta=25°C (Note 5)	_	1.0	_	рF

<sup>\*</sup> All typical values are at Ta=25°C,  $V_{CC}=5V$ ,  $I_{F(ON)}=3mA$  unless otherwise specified.

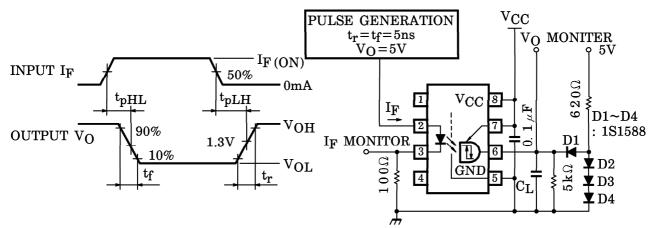
### SWITCHING CHARACTERISTICS (Unless Otherwise specified, $V_{CC} = 4.5 \sim 20V$ , $Ta = 25 ^{\circ}C$ )

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.*	MAX.	UNIT
Propagation Delay Time to Logic High Output (Note 7)	${ m t_{pLH}}$		$I_{\mathbf{F}} = 3 \rightarrow 0 \text{mA}$	_	250	400	ns
Propagation Delay Time to Logic Low Output (Note 7)	${ m t_{pHL}}$	1	$I_{\mathbf{F}} = 0 \rightarrow 3 \text{mA}$	_	270	400	ns
Output Rise Time (10-90%)	$t_r$		$I_F=3\rightarrow 0$ mA, $V_{CC}=5$ V	_	35	75	ns
Output Fall Time (90-10%)	$t_f$		$I_F = 0 \rightarrow 3mA, V_{CC} = 5V$		20	75	ns
Output Enable Time to Logic High	${}^{ m t}_{ m pZH}$		$V_E = 0 \rightarrow 3V$	_	-	1	ns
Output Enable Time to Logic Low	$t_{\mathrm{pZL}}$	2	$V_E = 0 \rightarrow 3V$	_	_	1	ns
Output Disable Time from Logic High	${ m t_{pHZ}}$	2	$V_E = 3 \rightarrow 0V$	_		1	ns
Output Disable Time from Logic Low	${}^{ m t}_{ m pLZ}$		$V_{\mathbf{E}} = 3 \rightarrow 0 V$	_	_	1	ns
Common Mode Transient Immunity at Logic High Output (Note 8)	C <sub>MH</sub>	3	I <sub>F</sub> =0mA, V <sub>CM</sub> =50V V <sub>O (Min.)</sub> =2V	1000	_		V/μs
Common Mode Transient Immunity at Logic Low Output (Note 8)	$\mathrm{c}_{\mathrm{ML}}$	ง	I <sub>F</sub> =1.6mA, V <sub>CM</sub> =50V V <sub>O (Max.)</sub> =0.8V	-1000	_	_	V/μs

<sup>\*</sup> All typical values are at Ta=25°C, V<sub>CC</sub>=5V

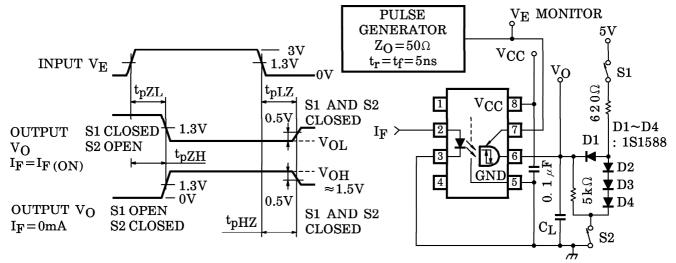
- (Note 6) Duration of output short circuit time should not exceed 10ms.
- (Note 7) The  $t_{pLH}$  propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.3V point on the leading edge of the output pulse. The  $t_{pHL}$  propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.3V point on the trailing edge of the output pulse.
- (Note 8)  $C_{ML}$  is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state ( $V_O > 0.8V$ ).  $C_{MH}$  is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic state ( $V_O > 2.0$ ).
- (Note 9) A ceramic capacitor  $(0.1\mu\text{F})$  should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1cm.

TEST CIRCUIT 1 :  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_{r}$  and  $t_{f}$ 



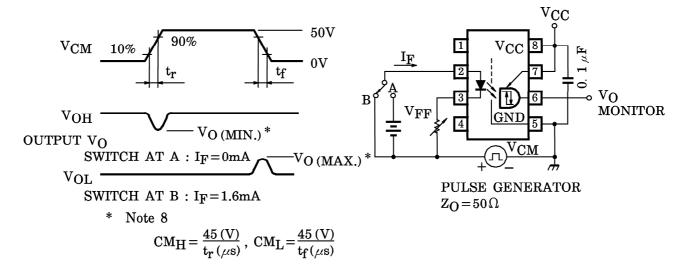
C<sub>L</sub> is approximately 15pF which includes probe and stray wiring capacitance.

TEST CIRCUIT 2: tpHZ, tpZH, tpLZ and tpZL



C<sub>L</sub> is approximately 15pF which includes probe and stray wiring capacitance.

TEST CIRCUIT 3: Common Mode Transient Immunity



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